NSN 5962-01-393-6094

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Maximum Bower Dissination Patings
Maximum Power Dissipation Rating: 1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Burn in and electrostatic sensitive and monolithic and ultraviolet erasable and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Control of the Control
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
13 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-9 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, programmed-uv eprom, 64k (8k x8)
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Memory Device Type:
Eprom
Special Features:
Electrostatic discharge sensitive; altered item, make from p/n 5962-8751501la
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

No

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